## NSN 5961-00-104-8394

No Fiig: A110a0



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-00-104-8394 **Inclosure Material:** Plastic **Overall Length:** 0.435 inches **Overall Height:** 0.135 inches **Overall Width:** 0.305 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Internal Junction Configuration:** Npn **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 breakdown voltage, collector-to-base, emitter open and 30.0 breakdown voltage, collector-to-emitter, base open and 4.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 2.00 amperes base current, dc and 3.00 amperes collector current, dc **Power Rating Per Characteristic:** 25.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**